

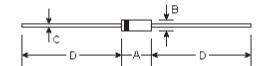
1N4942 THRU 1N4948

FAST SWITCHING PLASTIC RECTIFIER
Reverse Voltage - 200 to 1000 Volts
Forward Current - 1.0 Ampere

Features

- High temperature metallurgically bonded construction
- Hermetically sealed package
- 1.0 ampere operation at T_A=55 ^oC with no thermal runaway
- Typical I_R less than 0.1 μ Â
- Capable of meeting environmental standards of MIL-S-19500
- Fast switching for high efficiency
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3Kg) tension

DO-41



Mechanical Data

• Case: DO-41 solid plastic body

 Terminals: Plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: Color band denotes cathodeWeight: 0.012 ounce, 0.33 gram

DIMENSIONS										
DIM	inches		m	Note						
	Min.	Max.	Min.	Max.	Note					
Α	0.165	0.205	4.2	5.2						
В	0.079	0.106	2.0	2.7	ф					
С	0.028	0.034	0.71	0.86	ф					
D	1.000	-	25.40	-						

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

	Symbols	1N4942	1N4944	1N4946	1N4947	1N4948	Units
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	140	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	200	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at $\rm T_A$ =55 $^{\circ}\rm C$	I _(AV)	1.0					Amp
Peak forward surge current 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method)	I _{FSM}	25.0					Amps
Maximum instantaneous forward voltage at: 1.0A at: 2.0A, T_A =40 $^{\circ}$ C	V _F	1.3 2.5					Volts
Maximum DC reverse current at rated DC blocking voltage T _A =175 °C	I _R	1.0 500.0					μА
Maximum reverse recovery time (Note 1)	T _m	150 250 500			500	nS	
Typical junction capacitance (Note 2)	C _J	15.0					ρF
Typical thermal resistance (Note 3)	R _{⊚JA}	55.0					°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175					$^{\circ}$

Notes:

- (1) Reverse recovery test conditions: I_E=0.5A, I_D=1.0A, I_E=0.25A
- (2) Measured at 1.0MHz and applied reverse voltage of 4.0 volts
- $(3)\,Thermal\,resistance\,from\,junction\,to\,ambient\,at\,0.375"\,(9.5mm)\,lead\,length,\,P.C.B.\,mounted$

RATINGS AND CHARACTERISTIC CURVES

